ΡΛΝ	ĴΪΤ
	SEMI CONDUCTOR

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 42 A

Features

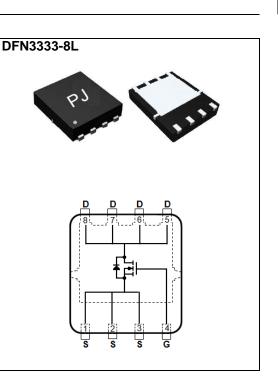
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@8A<11m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@6A<15m\Omega$
- Advanced Trench Process Technology

40 V

- High density cell design for ultralow on-resistance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN3333-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40		
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C		42		
	$T_{C}=100^{\circ}C$	Ι _D	26.5	А	
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	120		
Power Dissipation	T _C =25°C	Po	42	W	
	T _c =100°C		21		
Continuous Drain Current	T _A =25°C	I _D	10	A	
	T _A =70°C		8		
Power Dissipation	T _A =25°C	Po	2.4	W	
	T _A =70°C		1.6		
Operating Junction and Storage	Temperature Range	T _J ,T _{STG}	-55~175	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{ extsf{ heta}JC}$	3.57	°C/W	
	Junction to Ambient	R _{θJA}	62.5		

• Limited only By Maximum Junction Temperature





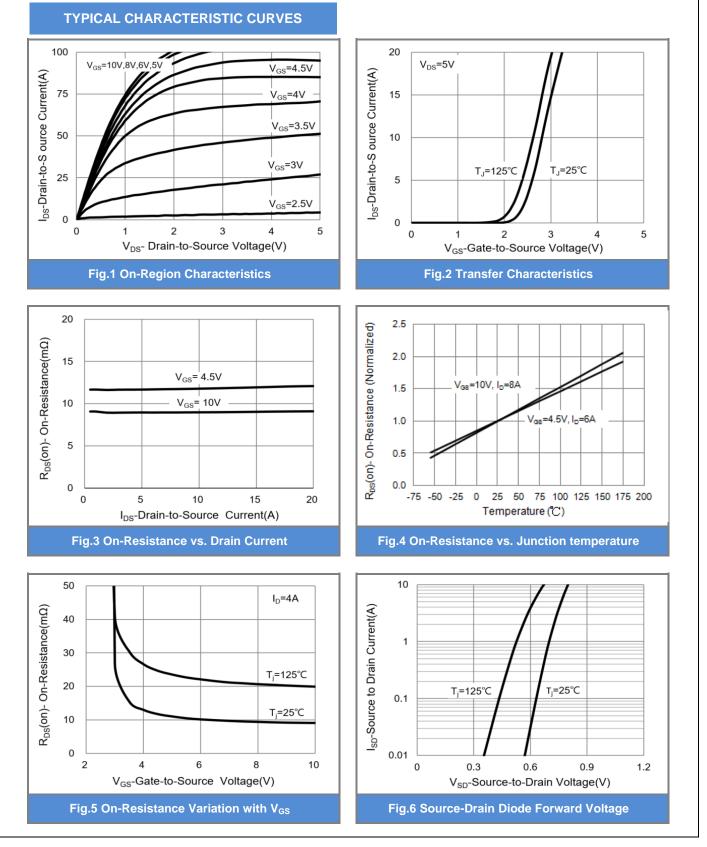
Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{DSS} V _{GS} =0V,I _D =250uA		-	-	v
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.0	1.75	2.5	V
Drain-Source On-State Resistance	D	V _{GS} =10V,I _D =8A	-	8.5	11	mΩ
	$R_{DS(on)}$	V _{GS} =4.5V,I _D =6A	-	11.5	15	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)		·				
Total Gate Charge	Qg	V _{DS} =20V, I _D =10A,	-	10	-	nC
Gate-Source Charge	Q_{gs}		-	3.5	-	
Gate-Drain Charge	Q _{gd}	V _{GS} =4.5V ^(Note 2,3)	-	3.6	-	
Input Capacitance	Ciss		-	1040	-	pF
Output Capacitance	Coss	$V_{DS}=20V, V_{GS}=0V,$	-	117	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	84	-	
Turn-On Delay Time	td _(on)	V _{DS} =20V, I _D =1A,	-	9.4	-	
Turn-On Rise Time	t _r	V_{GS} =10V, R _G =6Ω (Note 2,3)	-	19	-	ns
Turn-Off Delay Time	td _(off)		-	66	-	
Turn-Off Fall Time	t _f		-	67	-	
Drain-Source Diode						
Maximum Continuous Drain-Source				-	42	А
Diode Forward Current	I _S		-			
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.7	1	V

NOTES:

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

May 24,2019-REV.02



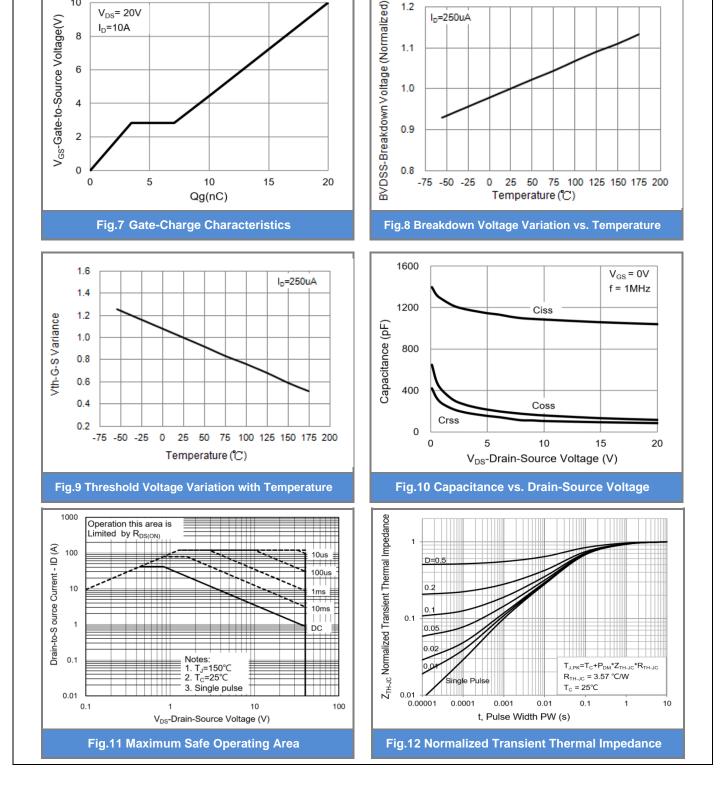


PJQ4448P-AU





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1.2

Ip=250uA

TYPICAL CHARACTERISTIC CURVES



10

8

PJQ4448P-AU

V_{DS}= 20V

 $I_D = 10A$

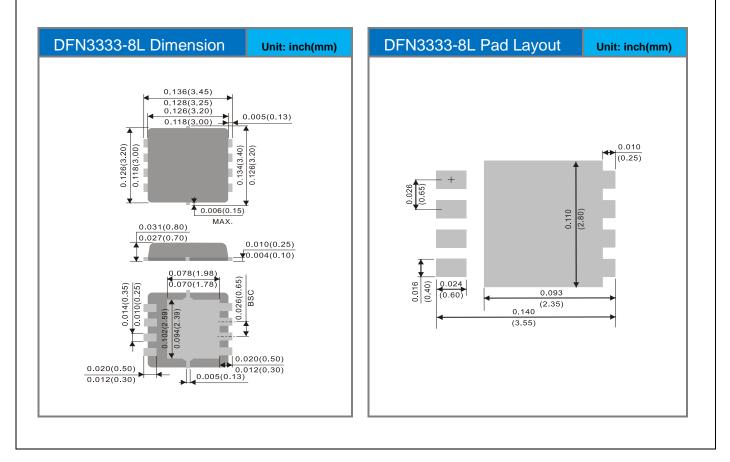




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ4448P-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4448	Halogen free

Packaging Information & Mounting Pad Layout





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